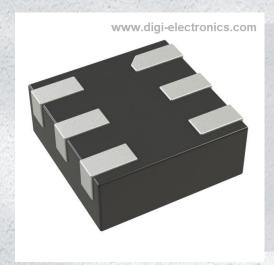


# MC74VHC1GT08MU3TCG Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MC74VHC1GT08MU3TCG-DG

Manufacturer onsemi

Manufacturer Product Number MC74VHC1GT08MU3TCG

Description IC GATE AND 1CH 2-INP 6UDFN

Detailed Description AND Gate IC 1 Channel 6-UDFN (1x1)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
MC74VHC1GT08MU3TCG	onsemi
Series:	Product Status:
74VHC	Active
Logic Type:	Number of Circuits:
AND Gate	1
Number of Inputs:	Features:
2	
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 5.5V	1 μΑ
Current - Output High, Low:	Input Logic Level - Low:
8mA, 8mA	0.5V ~ 1.65V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 3.85V	7.9ns @ 5V, 50pF
Operating Temperature:	Mounting Type:
-55°C ~ 125°C	Surface Mount
Supplier Device Package:	Package / Case:
6-UDFN (1x1)	6-UFDFN
Base Product Number:	
74VHC1GT08	

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

8542.39.0001



www.onsemi.com

## **Single 2-Input AND Gate**

## MC74VHC1G08, MC74VHC1GT08

The MC74VHC1G08 / MC74VHC1GT08 is a single 2 input AND gate in tiny footprint packages. The MC74VHC1G08 has CMOS-level input thresholds while the MC74VHC1GT08 has TTL-level input thresholds.

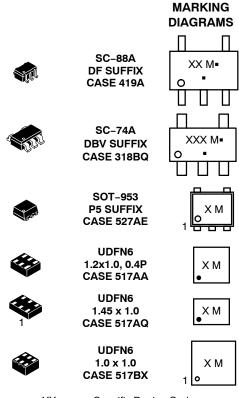
The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. Some output structures also provide protection when  $V_{CC} = 0 \ V$  and when the output voltage exceeds  $V_{CC}.$  These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

#### **Features**

- Designed for 2.0 V to 5.5 V V<sub>CC</sub> Operation
- 3.5 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



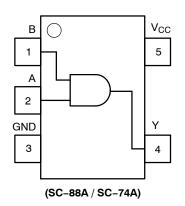
XX = Specific Device Code
M = Date Code\*
= Pb-Free Package

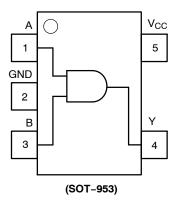
(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 7 of this data sheet.





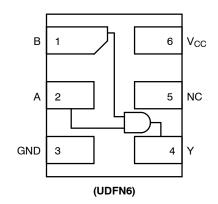


Figure 2. Pinout (Top View)

**PIN ASSIGNMENT** 

(SC-88A / SC-74A)

Pin	Function
1	В
2	Α
3	GND
4	Y
5	V <sub>CC</sub>

PIN ASSIGNMENT (SOT-953)

Pin	Function
1	Α
2	GND
3	В
4	Y
5	V <sub>CC</sub>

PIN ASSIGNMENT (UDFN)

Pin	Function
1	В
2	Α
3	GND
4	Y
5	NC
6	V <sub>CC</sub>

## **FUNCTION TABLE**

Inp	Output	
Α	В	Y
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

#### **MAXIMUM RATINGS**

Symbol	Characteristics		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	Tri–	(High or Low State) State Mode (Note 1) n Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
l <sub>ok</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin		±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
θЈА	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-553 SOT-953 UDFN6	377 320 324 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SC-74A SOT-553 SOT-953 UDFN6	332 390 386 491 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating Ox	ygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>		Human Body Model arged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.

2. Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.

3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to

- EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
- 4. Tested to EIA/JESD78 Class II.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Cha	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode ( $V_{\rm CC}$ = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1G08)

		Test	V <sub>CC</sub>	7	Γ <sub>A</sub> = 25°	С	-40°C ≤	T <sub>A</sub> ≤ 85°C	-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.5	_	_	1.5	-	1.5	-	V
	Voltage		3.0	2.1	_	_	2.1	-	2.1	-	
			4.5	3.15	-	-	3.15	-	3.15	-	
			5.5	3.85	-	-	3.85	-	3.85	-	
V <sub>IL</sub>	Low-Level Input		2.0	-	-	0.5	-	0.5	-	0.5	V
	Voltage		3.0	-	-	0.9	-	0.9	-	0.9	
			4.5	-	-	1.35	-	1.35	-	1.35	
			5.5	-	-	1.65	-	1.65	-	1.65	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -4  m\text{A} \\ &I_{OH} = -8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –	1 1 1 1	1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	<b>&gt;</b>
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 4  m\text{A} \\ &I_{OL} = 8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	_	-	±0.1	-	±1.0	-	±1.0	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0.0	_	_	1.0	-	10	_	10	μА
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	_	1.0	-	20	_	40	μΑ

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT08)

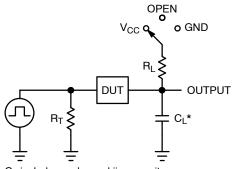
		Test	V <sub>CC</sub>	T <sub>A</sub> = 25°C			-40°C ≤	-40°C ≤ T <sub>A</sub> ≤ 85°C		-55°C ≤ T <sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.0	-	-	1.0	-	1.0	-	V
	Voltage		3.0	1.4	-	-	1.4	-	1.4	-	
			4.5	2.0	-	-	2.0	-	2.0	-	
			5.5	2.0	-	-	2.0	-	2.0	-	1
V <sub>IL</sub>	Low-Level Input		2.0	-	-	0.28	-	0.28	-	0.28	V
	Voltage		3.0	-	-	0.45	-	0.45	-	0.45	1
			4.5	-	-	0.8	-	0.8	-	0.8	
			5.5	-	-	0.8	-	0.8	-	0.8	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -4  m\text{A} \\ &I_{OH} = -8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –	- - - -	1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	_	±1.0	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	_	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	_	40	μΑ
I <sub>CCT</sub>	Increase in Quies- cent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **AC ELECTRICAL CHARACTERISTICS**

				Т	T <sub>A</sub> = 25°C -40		$T_A = 25^{\circ}C$ $-40^{\circ}C \leq T$		T <sub>A</sub> ≤ 85°C	-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	4.1	8.8	-	10.5	-	12.5	ns	
t <sub>PHL</sub>	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	5.9	12.3	-	14.0	-	16.5		
		C <sub>L</sub> = 15 pF	4.5 to 5.5	-	3.5	5.9	-	7.0	-	9.0		
		C <sub>L</sub> = 50 pF		_	4.2	7.9	-	9.0	-	11.0		
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF	
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	-	-	-	-	-	pF	
Symbol	Parameter							Typical (	@ 25°C, V <sub>C</sub>	c = 5.0 V	Unit	
C <sub>PD</sub>	Power Dissipation Ca	pacitance (Not	e 5)						8.0		pF	

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



Test	Switch Position	C <sub>L</sub> , pF	$R_L, \Omega$
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table	Х
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>		1 k
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND		1 k

X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 3. Test Circuit

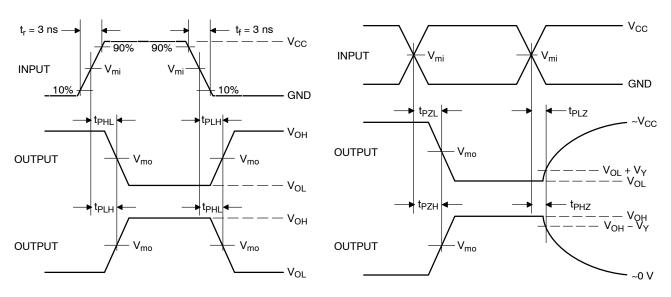


Figure 4. Switching Waveforms

		V <sub>mo</sub> , V		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

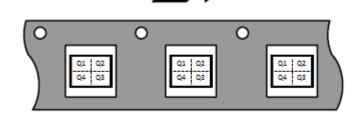
### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G08DFT1G	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DFT1G-Q*	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G-Q*	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G-Q*	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G-Q*	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G-Q*	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G-Q*	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08P5T5G	SOT-953	E	Q2	8000 / Tape & Reel
MC74VHC1GT08P5T5G	SOT-953	Р	Q2	8000 / Tape & Reel
MC74VHC1G08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	K (Rotated 180° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	4 (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1G08MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	2	Q4	3000 / Tape & Reel
MC74VHC1G08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	D (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	K	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

### **PIN 1 ORIENTATION IN TAPE AND REEL**

## Direction of Feed



Specifications Brochure, BRD8011/D.

\*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



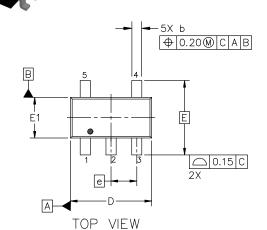
## **MECHANICAL CASE OUTLINE**

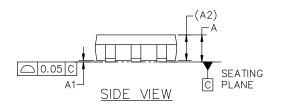
PACKAGE DIMENSIONS

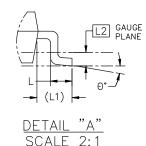
## SC-74A-5 3.00x1.50x0.95, 0.95P

CASE 318BQ ISSUE C

**DATE 26 FEB 2024** 







### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code M

= Pb-Free Package

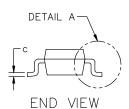
(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

#### NOTES:

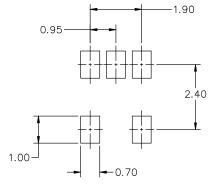
- DIMENSIONING AND TOLERANCING CONFORM TO ASME 1. Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DIM



DIM	MIN.	NOM.	MAX.
Α	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2	(	0.95 REF	
b	0.25	0.37	0.50
С	0.10	0.18	0.26
D	2.85	3.00	3.15
Е	:	2.75 BSC	;
E1	1.35	1.50	1.65
е	(	0.95 BSC	;
L	0.20	0.40	0.60
L1	0.62 REF.		
L2	0.25 BSC		
Θ	0,	5*	10°

**MILLIMETERS** 



### RECOMMENDED MOUNTING FOOTPRINT\*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-74A-5 3.00x1.50x0.95,	SC-74A-5 3.00x1.50x0.95, 0.95P	

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## **MECHANICAL CASE OUTLINE**

PACKAGE DIMENSIONS



#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

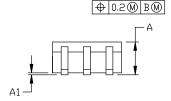
**DATE 11 APR 2023** 

#### NOTES:

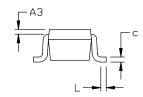
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

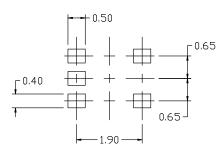
DIM	MILLIMETERS		
INITU	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3	0.20 REF		
b	0.10	0.20	0.30
C	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30

## е Ε1 0



5X b





#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
<ol><li>EMITTER</li></ol>
3. BASE
<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR</li></ol>

STYLE 6:

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE

3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

PIN 1	. EMITTER 2
2	2. BASE 2
3	s. EMITTER 1
4	. COLLECTOR
5	<ol><li>COLLECTOR 2/BASE 1</li></ol>

STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR

STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER

PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5 ANODE

STYLE 9:

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

### **DOCUMENT NUMBER:**

98ASB42984B

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**DESCRIPTION:** 

SC-88A (SC-70-5/SOT-353)

PAGE 1 OF 1

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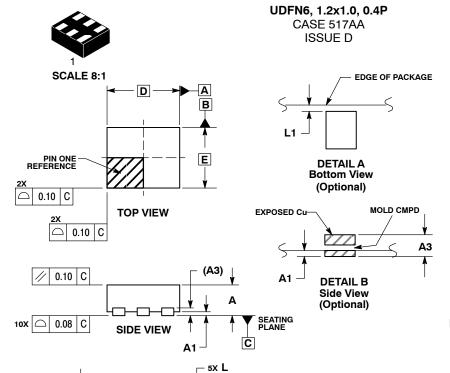
6X **b** 

0.10 | C | A | B

0.05 C

NOTE 3

## MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



е

**BOTTOM VIEW** 

**DATE 03 SEP 2010** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER
  ASME Y14 5M 1994
- ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL
   AND IS MEASURED BETWEEN 0.25 AND
   CONTROL TERMINAL
- 0.30 mm FROM TERMINAL.
   COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	<b>MILLIMETERS</b>		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
А3	0.127	REF	
b	0.15 0.25		
D	1.20 BSC		
E	1.00 BSC		
е	0.40 BSC		
L	0.30 0.40		
L1	0.00	0.15	
L2	0.40	0.50	

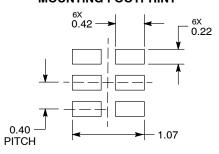
## GENERIC MARKING DIAGRAM\*



X = Specific Device CodeM = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

### **MOUNTING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	6 PIN UDFN, 1.2X1.0, 0.4P		PAGE 1 OF 1

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6X 🗀

0.05 C

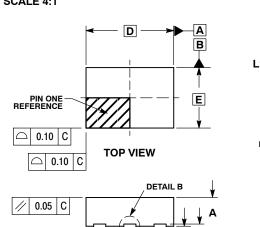
### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS

NOTES:
1. DIMENSIONING AND TOLERANCING PER

ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

## UDFN6, 1.45x1.0, 0.5P CASE 517AQ **ISSUE 0**

**DATE 15 MAY 2008** 



SIDE VIEW

е

**A**1

**A2** 

6X b

Ф

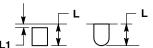
0.10

CAB

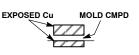
0.05 C NOTE 3

6X L

C SEATING PLANE



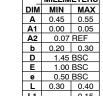
**DETAIL A** OPTIONAL CONSTRUCTIONS



OPTIONAL

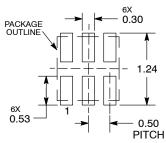
CONSTRUCTIONS

**DETAIL B** 



MILLIMETERS

### **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

### **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 

XM

Χ = Specific Device Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	UDFN6, 1.45x1.0, 0.5P		PAGE 1 OF 1

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



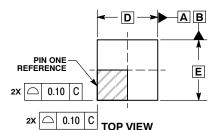
## **MECHANICAL CASE OUTLINE**

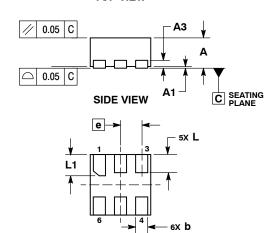
PACKAGE DIMENSIONS



UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

**DATE 18 MAY 2011** 





0.10 M C A B

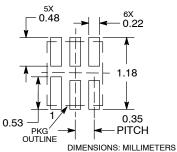
0.05 M C NOTE 3

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF
- BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13	REF	
b	0.12 0.22		
D	1.00 BSC		
E	1.00 BSC		
е	0.35 BSC		
L	0.25	0.35	
L1	0.30 0.40		

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 



X = Specific Device Code

M = Date Code

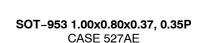
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	UDFN6, 1x1, 0.35P		PAGE 1 OF 1

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### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS



**ISSUE F** 



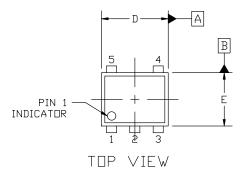
**DATE 17 JAN 2024** 

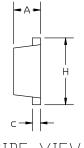
MAX

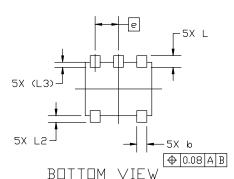
0.40

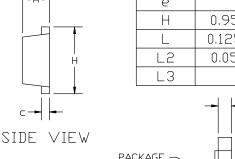
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



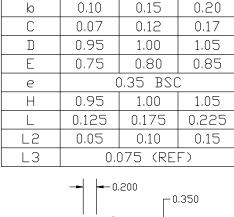






DIM

Α



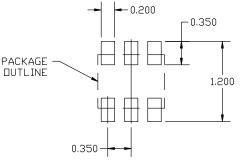
MILLIMETERS

 $N\square M$ 

0.37

MIN

0.34



## RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

### **GENERIC MARKING DIAGRAM\***



= Specific Device Code

= Month Code

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DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 1

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